#### DISCRETE SEMICONDUCTORS

## DATA SHEET

# **BYV40E series**Rectifier diodes ultrafast, rugged

**Product specification** 

September 2018



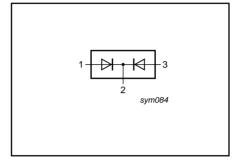
## Rectifier diodes ultrafast, rugged

**BYV40E** series

#### **FEATURES**

- Low forward volt drop
- · Fast switching
- Soft recovery characteristic
- Reverse surge capability
- High thermal cycling performance
- low profile surface mounting package

#### **SYMBOL**



#### **QUICK REFERENCE DATA**

$$V_R = 150 \text{ V}/200 \text{ V}$$
 $V_F \le 0.7 \text{ V}$ 
 $I_{O(AV)} = 1.5 \text{ A}$ 
 $I_{RRM} = 0.1 \text{ A}$ 
 $t_{rr} \le 25 \text{ ns}$ 

#### **GENERAL DESCRIPTION**

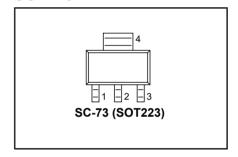
Dual, common cathode, ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV40E series is supplied in the SOT223 surface mounting package.

#### **PINNING**

PIN DESCRIPTION		
1	anode 1	
2	cathode	
3	anode 2	
tab	cathode	

#### **SOT223**



#### **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER CONDITIONS MIN		MIN.	I. MAX.		UNIT
V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	Peak repetitive reverse voltage Crest working reverse voltage Continuous reverse voltage	$\textbf{BYV40E}$ $T_{sp} \leq 120 ^{\circ} \text{C}$	1 1 1	<b>-150</b> 150 150 150	<b>-200</b> 200 200 200	V V V
I <sub>O(AV)</sub>	Repetitive peak forward current	$T_{sp} \le 132^{\circ}C$ $t = 25 \ \mu s; \ \delta = 0.5;$	-		.5 .5	A A
I <sub>FSM</sub>	per diode Non-repetitive peak forward current per diode	$T_{sp} \le 132$ °C $t_p = 10$ ms $t_p = 8.3$ ms $t_p = 8.3$ ms $t_p = 8.3$ ms $t_p = 150$ °C prior $t_p = 150$ °C prior $t_p = 150$ °C prior	-	6	6 .6	A A
I <sub>RRM</sub>	Repetitive peak reverse current per diode	$t_p = 2 \mu s; \delta = 0.001$	-	0	.1	Α
I <sub>RSM</sub>	Non-repetitive peak reverse current per diode	t <sub>p</sub> = 100 μs	-	0	.1	Α
$T_{stg}$ $T_{j}$	Storage temperature Operating junction temperature		-65 -		50 50	°C °C

<sup>1</sup> Neglecting switching and reverse current losses

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#### **ESD LIMITING VALUE**

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>C</sub>	Electrostatic discharge capacitor voltage	Human body model; C = 250 pF; R = 1.5 kΩ	-	8	kV

#### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-sp</sub>	Thermal resistance	one or both diodes conducting	-	-	15	K/W
R <sub>th j-a</sub>	junction to solder point Thermal resistance junction to ambient	pcb mounted; minimum footprint pcb mounted; pad area as in fig:11	- -	156 70	- -	K/W K/W

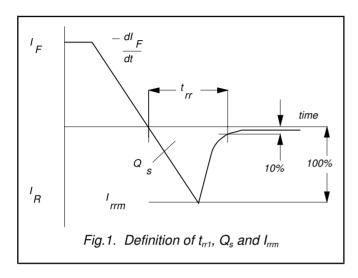
#### **ELECTRICAL CHARACTERISTICS**

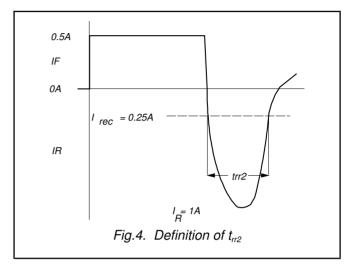
characteristics are per diode at T<sub>i</sub> = 25 °C unless otherwise stated

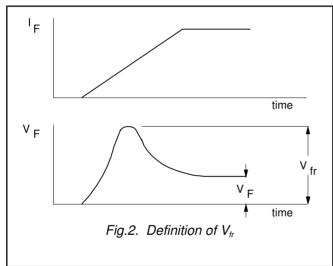
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	Forward voltage	$I_F = 0.5 \text{ A}; T_j = 150^{\circ}\text{C}$	-	0.50	0.7	V
1,	Reverse current	$ I_F = 1.5 \text{ A}  $ $ V_R = V_{RWM}; T_i = 100 \text{ °C}$	-	0.82 100	1.0 300	V μA
¹R	Treverse current	$V_R = V_{RWM}$ , $V_j = 100$ C $V_R = V_{RWM}$	-	5	10	μΑ
$Q_s$	Reverse recovery charge	$ I_{\rm F}  = 2 \text{ A}; V_{\rm R} \ge 30 \text{ V}; -dI_{\rm F}/dt = 20 \text{ A/}\mu\text{s}$	-	-	11	'nC
t <sub>rr1</sub>	Reverse recovery time	$I_F = 1 \text{ A}; V_R \ge 30 \text{ V};$	-	-	25	ns
t <sub>rr2</sub> V <sub>fr</sub>	Reverse recovery time Forward recovery voltage	$-dI_F/dt = 100 \text{ A/}\mu\text{s}$ $I_F = 0.5 \text{ A to } I_R = 1 \text{ A; } I_{rec} = 0.25 \text{ A}$ $I_F = 2 \text{ A; } dI_F/dt = 20 \text{ A/}\mu\text{s}$	-	10 3	20 -	ns V

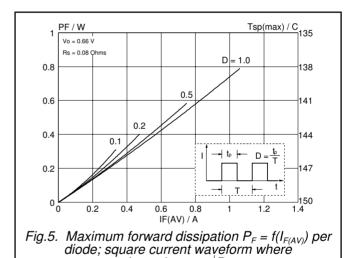
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 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}$ .

Voltage Pulse Source

Current shunt to 'scope

Fig.3. Circuit schematic for t<sub>rr2</sub>

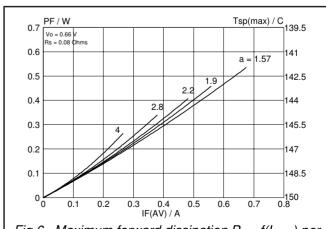
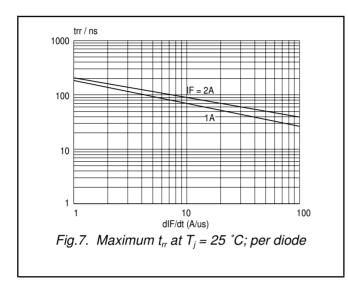


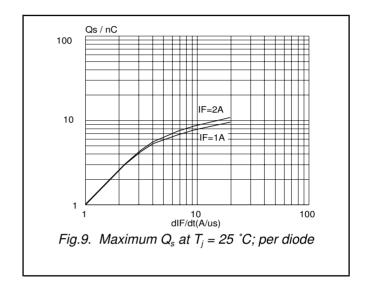
Fig.6. Maximum forward dissipation  $P_F = f(I_{F(AV)})$  per diode; sinusoidal current waveform where a = form factor  $= I_{F(RMS)} / I_{F(AV)}$ .

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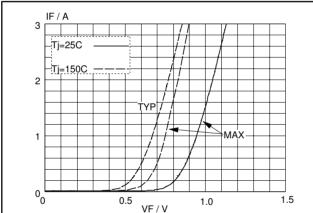


Fig.8. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 

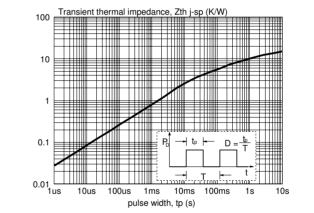


Fig.10. Transient thermal impedance; per diode;  $Z_{th j-sp} = f(t_p)$ .

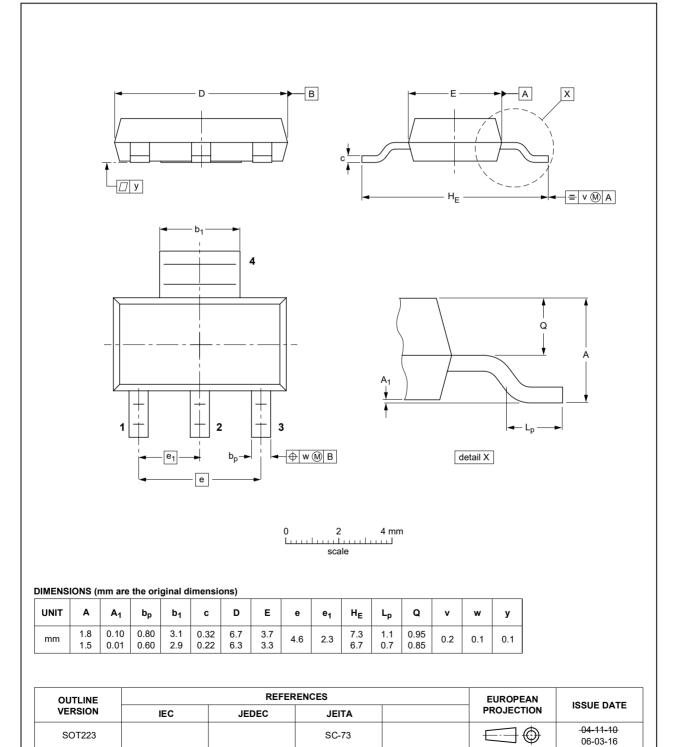
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#### **MECHANICAL DATA**



**SOT223** 



#### Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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